	Туре	L #	Hits	Search Text	DBs	Time Stamp	Comment
1	BRS	L1	4	wang near chia-chung.in.		2004/09/2 3 16:19	
2	BRS	L2	106	lin near charles.in.	USPAT; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/09/2 3 16:27	
3	BRS	L3	5243	(semiconductor) near35 (trace)	USPAT; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/09/2 3 16:28	

	Туре	L #	Hits	Search Text	DBs	Time Stamp	Comment s
4	BRS	L4	1403	(semiconductor) near35 (conductive near trace)		2004/09/2 3 16:29	
5	BRS	L5	526	(semiconductor) near35 (conductive near trace) near35 (pad)	USPAT; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/09/2 3 16:29	
6	BRS	L6	122	(semiconductor) near35 (conductive near trace) near35 (pad) near50 (cavity or recess or opening or hole or aperture)	USPAT; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/09/2 3 16:59	

	Туре	L #	Hits	Search Text	DBs	Time Stamp	Comment
7	BRS	L7	515	(conductive near trace) near35 (pad) near50 (cavity or recess or opening or hole or aperture)	USPAT; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/09/2 3 17:00	
8	BRS	L8	4114	(chip or die or device) near35 (trace) near35 (substrate or wafer)	USPAT; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/09/2 3 17:36	
9	BRS	L9	1671	(chip or die or device) near35 (conductive near trace) near35 (substrate or wafer)	USPAT; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/09/2 3 17:37	

	Туре	L #	Hits	Search Text	DBs	Time Stamp	Comment s
10	BRS	L10	231	(chip or die or device) near35 (conductive near trace) near35 (substrate or wafer) near50 (hole or aperture or cavity or recess or opening)	USPAT; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/09/2 3 17:37	
11	BRS	L12	12	· · · · · · · · · · · · · · · · · · ·	USPAT; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/09/2 3 17:38	
12	BRS	L11	99	(chip or die or device) near35 (conductive near trace) near35 (substrate or wafer) near50 (hole or aperture or cavity or recess or opening) near35 (pad\$1)	USPAT; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/09/2 3 17:39	

	U	1	Document ID	Title	Current OR	Pages
1			US 20040159957 A1	Interposer substrate and wafer scale interposer substrate member for use with flip-chip configured semiconductor dice	257/778	32
2	⊠		US 20030166312 A1	Methods for assembly and packaging of flip chip configured dice with interposer	438/107	27
3	⊠		US 20030164548 A1	Flip chip packaging using recessed interposer terminals	257/738	29
4	⊠		US 20030164541 A1	Method and apparatus for dielectric filling of flip chip on interposer assembly	257/686	34
5	⊠	1	US 20020079593 A1	Semiconductor package having heat sink attached to substrate	257/778	8
6			US 6528876 B2	Semiconductor package having heat sink attached to substrate	257/706	8
7			US 6475833 B2 .	Bumpless flip chip assembly with strips and via-fill	438/121	16
8			US 6437452 B2	Bumpless flip chip assembly with strips-in-via and plating	257/784	18

	U	1	Do	cument ID	Title	Current OR	Pages
9			US B2	6403400	Bumpless flip chip assembly with strips-in-via and plating	438/121	19
10			US B1	6316830	Bumpless flip chip assembly with strips and via-fill	257/737	13 [*]
11			US	5981873 A	Printed circuit board for ball grid array semiconductor package	174/52.2	10
12			US	6316830 B	Flip chip assembly for ball grid array package, includes electrically conductive material in through-holes on dielectric substrate, for electrically connecting conductive traces to terminal pads		13